

IFW



PATENT
Customer No. 22,852
Attorney Docket No. 03180.0326

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Write Application of:)
)
Tadashi IGUCHI et al.) Group Art Unit: 2826
)
Application No.: 10/612,033) Examiner: Quinto, Kevin V.
)
Filed: July 3, 2003)
)
For: SEMICONDUCTOR MEMORY) Confirmation No.: 5852
PREVENTING AN ELECTRIC)
SHORT CIRCUIT BETWEEN A)
WORD LINE AND A)
SEMICONDUCTOR SUBSTRATE,)
AND MANUFACTURING)
METHOD FOR THE)
SEMICONDUCTOR MEMORY (As)
Amended)

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

AMENDMENT

In reply to the Office Action mailed February 9, 2005, the period for response to which extends through May 9, 2005, Applicants submit the following amendments and remarks. This Amendment accompanies the filing of an Information Disclosure Statement.

Amendments to the Claims are reflected in the listing of claims beginning on page 2 of this paper.

Remarks begin on page 8 of this paper.